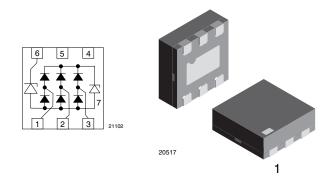
Vishay Semiconductors

USB-OTG BUS-Port ESD-Protection for $V_{BUS} = 12 V$



MARKING (example only)

SHA



Dot = Pin 1 marking XX = Date code

YY = Type code (see table below)

- Ultra compact LLP75-7L package
- Low package height < 0.6 mm
- 3-line USB ESD-protection with max. working range = 5.5 V
- + V_{BUS} protection with 12 V working range
- Low leakage current
- Low load capacitance $C_D = 0.7 \text{ pF}$
- ESD-protection to IEC 61000-4-2
- ± 15 kV contact discharge ± 15 kV air discharge
- Surge current acc. IEC 61000-4-5 IPP > 3 A
- e4 precious metal (e.g. Ag, Au, NiPd, NiPdAu) (no Sn)
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

ORDERING INFORMATION					
DEVICE NAME	ORDERING CODE TAPED UNITS PER (8 mm TAPE ON 7"		MINIMUM ORDER QUANTITY		
VBUS053AZ-HAF	VBUS053AZ-HAF-GS08	15 000	15 000		

PACKAGE DATA							
DEVICE NAME	PACKAGE NAME	TYPE CODE	WEIGHT	MOLDING COMPOUND FLAMMABILITY RATING	MOISTURE SENSITIVITY LEVEL	SOLDERING CONDITIONS	
VBUS053AZ-HAF	LLP75-7L	U9	4.2 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals	

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT		
Data line D+, D-, ID: Pin 1, 2	and 3 to ground (pin 7)					
Peak pulse current	acc. IEC 61000-4-5; $t_p = 8/20 \ \mu s$; single shot	I _{PPM} 3		А		
Peak pulse power	acc. IEC 61000-4-5; $t_p = 8/20 \ \mu s$; single shot	P _{PP}	36	W		
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V _{ESD}	± 15	kV		
	Air discharge acc. IEC 61000-4-2; 10 pulses	V _{ESD}	± 15	kV		
V _{BUS} : Pin 6 to ground (pin 7)					
Peak pulse current	acc. IEC 61000-4-5; tp = 8/20 µs/single shot	I _{PPM}	8	А		
Peak pulse power	acc. IEC 61000-4-5; tp = 8/20 µs/single shot	P _{PP}	240	W		
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V _{ESD}	± 30	kV		
	Air discharge acc. IEC 61000-4-2; 10 pulses	V _{ESD}	± 30	kV		
Operating temperature	Junction temperature	TJ	- 40 to + 125	°C		
Storage temperature		T _{STG}	- 55 to + 150	°C		

** Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902



VBUS053AZ-HAF

Vishay Semiconductors USB-OTG BUS-Port ESD-Protection for $V_{BUS} = 12 V$



UNIT lines μΑ ν ν ν ν ν ν

pF

pF

0.1

0.5

ELECTRICAL CHARACTERISTICS All inputs (pin 1, 2, and 3) to ground (pin 7)								
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.			
Protection paths	Number of lines which can be protected	N _{channel}	-	-	3			
Reverse working voltage	at I _R = 0.1 μA	V _{RWM}	5.5	-	-			
Reverse current	at $V_R = V_{RWM} = 3.3 \text{ V}; \text{ T} = 65 ^{\circ}\text{C}$	I _R	-	-	0.085			
	at V _R = V _{RWM} = 5.5 V	I _R	-	-	1			
Forward voltage	at I _F = 15 mA	VF	0.7	-	1.2			
Reverse breakdown voltage	at I _R = 1 mA	V _{BR}	6.5	-	10			
Reverse clamping voltage	at I _{PP} = 1 A; acc. IEC 61000-4-5; T = 25 °C	V _C	-	10	12			
	at I _{PP} = 3 A; acc. IEC 61000-4-5; T = 25 °C	Vc	-	15	18			
Forward clamping voltage	at I _F = 3 A; acc. IEC 61000-4-5	V _F	-	3.4	4.1			
Line capacitance	Test pin at $V_R = 0 V$; any other I/O pin at $V_R = 3.3 V$, f = 1 MHz	C _D	-	0.7	1			

Difference of the line capacitance

Among pins 1, 2 and 3

at $V_R = 0$ V; f = 1 MHz

Note

Line symmetry

Line to line capacitance

• Tamb = - 40 °C to 85 °C, unless otherwise specified

ELECTRICAL CHARACTERISTICS V _{BUS} (pin 6) to ground (pin 7)						
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of line which can be protected	N _{channel}	-	-	1	line
Reverse working voltage	at I _R = 100 nA	V _{RWM}	12	-	-	V
Reverse current	at $V_R = V_{RWM} = 12 V$	I _R	-	-	100	nA
Forward voltage	at I _F = 10 mA	V _F	0.6	0.75	0.9	V
Reverse breakdown voltage	at I _R = 1 mA	V _{BR}	15	-	18	V
Reverse clamping voltage	at I _{PP} = 1 A; acc. IEC 61000-4-5; T = 25 °C	V _C	-	17.5	20	V
	at I _{PP} = 8 A; acc. IEC 61000-4-5; T = 25 °C	V _C	-	25	30	V
Forward clamping voltage	at I _F = 8 A; acc. IEC 61000-4-5	V _F	-	-	2.2	V
Line capacitance	at $V_R = 0 V$, f = 1 MHz	CD	-	70	85	pF

 dC_{D}

 C_{DD}

-

_

-

0.35

Note

• Tamb = - 40 °C to 85 °C, unless otherwise specified



USB-OTG BUS-Port ESD-Protection Vishay Semiconductors

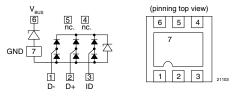
for $V_{BUS} = 12 V$

APPLICATION NOTE

The VBUS053AZ-HAF is intended as an ESD-protection and transient voltage suppressor for one USB-OTG port.

The LLP75-7L package contains two separate dies which are mounted on a common ground plane (pin 7). The high-speed data lines D-, D+ and ID, are connected to any of the pins no. 1 to 3. As long as the signal voltage on the data lines is between the ground- and the 5 V working range, the low capacitance PN-diodes offer a very high isolation to ground and to the other data lines. But as soon as any transient signal like an ESD-signal, exceeds this working range of 5 V in either the positive or negative direction, one of the PN-diodes gets into the forward mode and clamps the transient either to ground or to the avalanche break through level. An extra avalanche diode (separate die) clamps the supply line voltage (V_{BUS} at pin 6) above the 12 V working range to ground (pin 7).

Due to the "two die construction" the V_{BUS} line has a very high isolation to the data lines. In case of a destructive transient signal, i.e. coming from a charger, the data lines will not be influenced.



Remark:

The input pins no. 1, 2 and 3 are symmetrical. Each of the data signals D-, D+ and ID can be connected to pin 1, 2 or 3.

TYPICAL CHARACTERISTICS (Tamb = 25 °C, unless otherwise specified)

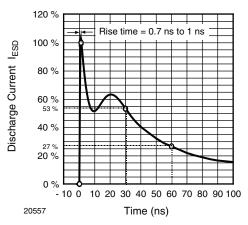


Fig. 1 - ESD Discharge Current Wave Form acc. IEC 61000-4-2 (330 Ω/150 pF)

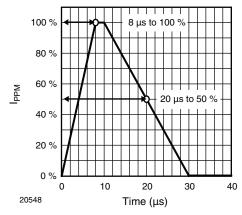


Fig. 2 - 8/20 µs Peak Pulse Current Wave Formacc. IEC 61000-4-5

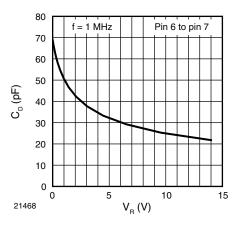
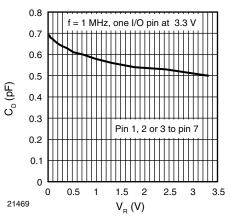
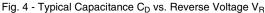


Fig. 3 - Typical Capacitance C_D vs. Reverse Voltage V_R





VBUS053AZ-HAF

Vishay Semiconductors USB-OTG BUS-Port ESD-Protection

or V_{BUS} = 12 V



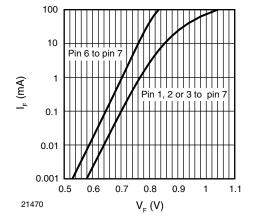


Fig. 5 - Typical Forward Current I_F vs. Forward Voltage V_F

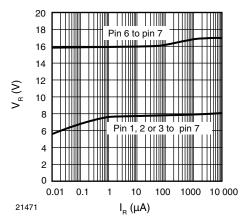


Fig. 6 - Typical Reverse Voltage V_{R} vs. Reverse Current I_{R}

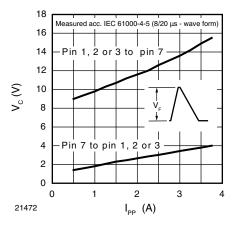


Fig. 7 - Typical Peak Clamping Voltage V_C vs. Peak Pulse Current I_{PP}

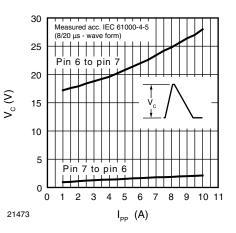
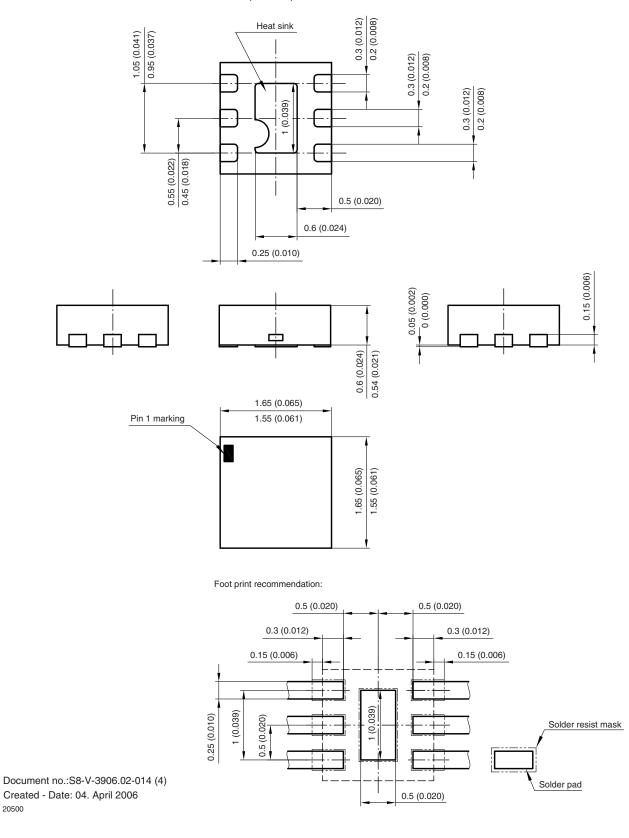


Fig. 8 - Typical Peak Clamping Voltage $V_C \, vs.$ Peak Pulse Current I_{PP}



USB-OTG BUS-Port ESD-Protection Vishay Semiconductors for $V_{BUS} = 12 V$

PACKAGE DIMENSIONS in millimeters (inches): LLP75-7L





Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.